

## WHAT IS CLAIMED IS:

1. A thin-film transistor liquid crystal display (TFT-LCD) substrate, comprising:

5 a substrate, which is defined to form a thin-film transistor (TFT) and a contact plug thereon, wherein the source/drain of the TFT is electrically coupled with the contact plug; and

a planarization layer, which is disposed on the substrate and comprises a via hole for penetrating the planarization layer to expose to the contact plug;

10 wherein the configuration of the cross-section of the via hole includes a straight edge so that the via hole is formed with a taper at a lateral view by reflow.

2. The TFT-LCD substrate according to claim 1, wherein the configuration of the cross-section of the via hole is non-circular shaped.

15 3. The TFT-LCD substrate according to claim 1, wherein the via hole is formed by a photolithography process and the pattern of the via hole is determined in accordance with the mask used during the photolithography process.

4. The TFT-LCD substrate according to claim 1, further comprising a dielectric material layer deposited at the inner surface of the via hole within

the planarization layer and electrically coupled with the contact plug.

5. The TFT-LCD substrate according to claim 4, wherein the dielectric material layer is made of Indium Tin Oxide (ITO).

6. A thin-film transistor liquid crystal display (TFT-LCD) substrate,  
5 comprising:

a substrate, which is defined to form a thin-film transistor (TFT) and a contact plug thereon, wherein the source/drain of the TFT is electrically coupled with the contact plug;

a passivation layer, which is deposited on the substrate;

10 a planarization layer, which is disposed on the passivation layer, wherein the passivation layer and the planarization layer have a via hole for penetrating both the passivation layer and the planarization layer to expose to the contact plug;

15 wherein the configuration of the cross-section of the via hole includes a straight edge so that the via hole is formed with a taper at a lateral view by reflow.

7. The TFT-LCD substrate according to claim 6, wherein the configuration of the cross-section of the via hole is non-circular shaped.

8. The TFT-LCD substrate according to claim 6, wherein the via hole is

formed by a photolithography process and the pattern of the via hole is determined in accordance with the mask used during the photolithography process.

9. The TFT-LCD substrate according to claim 6, further comprising a  
5 dielectric material layer deposited at the inner surface of the via hole within the planarization layer and electrically coupled with the contact plug.

10. The TFT-LCD substrate according to claim 9, wherein the dielectric material layer is made of Indium Tin Oxide (ITO).

11. A structure of the via hole within a planarization layer, the structure  
10 comprising :

a substrate, which is defined to form a thin-film transistor (TFT) and a contact plug thereon, wherein the source/drain of the TFT is electrically coupled with the contact plug; and

a planarization layer, which is disposed on the substrate and comprises a  
15 via hole for penetrating the planarization layer to expose to the contact plug;

wherein the configuration of the cross-section of the via hole includes a straight edge so that the via hole is formed with a taper at a lateral view by reflow.

12. The structure of the via hole within a planarization layer according to

claim 11, wherein the configuration of the cross-section of the via hole is non-circular shaped.

13. The structure of the via hole within a planarization layer according to claim 11, wherein the via hole is formed by a photolithography process and  
5 the pattern of the via hole is determined in accordance with the mask used during the photolithography process

14. The structure of the via hole within a planarization layer according to claim 11, further comprising a dielectric material layer deposited at the inner  
10 surface of the via hole within the planarization layer and electrically coupled with the contact plug.

15 . The structure of the via hole within a planarization layer according to claim 11, wherein the structure of the via hole within a planarization layer is applied to a thin-film transistor liquid crystal display (TFT-LCD) substrate.

16. A structure of the via hole within a planarization layer and a  
15 passivation layer, the structure comprising :

a substrate, which is defined to form a thin-film transistor (TFT) and a contact plug thereon, wherein the source/drain of the TFT is electrically coupled with the contact plug;

a passivation layer, which is deposited on the substrate;

a planarization layer, which is disposed on the passivation layer, wherein the passivation layer and the planarization layer have a via hole for penetrating both the passivation layer and the planarization layer to expose to the contact plug;

5 wherein the configuration of the cross-section of the via hole includes a straight edge so that the via hole is formed with a taper at a lateral view by reflow.

17. The structure of the via hole within a planarization layer and a passivation layer according to claim 16, wherein the configuration of the  
10 cross-section of the via hole is non-circular shaped.

18. The structure of the via hole within a planarization layer and a passivation layer according to claim 16, wherein the via hole is formed by a photolithography process and the pattern of the via hole is determined in accordance with the mask used during the photolithography process.

15 19. The structure of the via hole within a planarization layer and a passivation layer according to claim 16, further comprising a dielectric material layer deposited at the inner surface of the via hole within the planarization layer and electrically coupled with the contact plug.

20 20. The structure of the via hole within a planarization layer and a passivation layer according to claim 16, wherein the structure of the via hole within a planarization layer and a passivation layer applied to a thin-film

transistor liquid crystal display (TFT-LCD) substrate.

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